



### Rev.02 - 23 December 2019

**Product data sheet** 

### **1. General description**

Planar passivated very sensitive gate four quadrant triac in a TO92 plastic package. This very sensitive gate "series D" triac is intended for interfacing with low power drivers including microcontrollers.

### 2. Features and benefits

- Direct interfacing to logic level ICs
- · Direct interfacing with low power gate drivers and microcontrollers
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- · Very sensitive gate
- Triggering in all four quadrants

### 3. Applications

- Air conditioner indoor fan control
- General purpose low power motor control
- · General purpose switching and phase control

### 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	-	600	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 51 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	1	A
I <sub>TSM</sub> non-repetitive peak on- state current		full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	-	13.7	А
T <sub>j</sub>	junction temperature		-	-	125	°C
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I <sub>GT</sub>	gate trigger current	$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>i</sub> = 25 °C; <u>Fig. 7</u>	-	-	5	mA

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		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	7	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	1.3	10	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.4 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic	characteristics					
$      dV_{\text{D}}/dt  \  \  \text{rate of rise of off-state}  \  \  V_{\text{DM}} = 402 \text{ V};  \text{T}_{\text{j}} = 125 ^{\circ}\text{C};  (\text{V}_{\text{DM}} = 67\%   \text{of } \text{V}_{\text{DRM}}); \text{ exponential waveform}; \\ \text{R}_{\text{GT1(ext)}} = 1   \text{k}\Omega $		20	-	-	V/µs	
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_D = 400 \text{ V};  \text{T}_\text{j} = 125 \text{ °C};  \text{dI}_\text{com}/\text{dt} = 0.5 \text{ A/ms};$ $\text{I}_T = 1 \text{ A}; \text{ gate open circuit}$	3	-	-	V/µs

# **5. Pinning information**

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T2	main terminal 2		
2	G	gate		T2-T1
3	T1	main terminal 1	)               TO-92 (SOT54)	sym051

# 6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
BT131-600D	TO92	BT131-600D,412	Bulk	1000	SOT54	14-Nov-2013		
BT131-600D	TO92	BT131-600DQP	Reel	2000	SOT54	14-Nov-2013		
BT131-600D/L01	TO92	BT131-600D/L01EP	Bulk	500	SOT54/L01	14-Nov-2013		

## 7. Marking

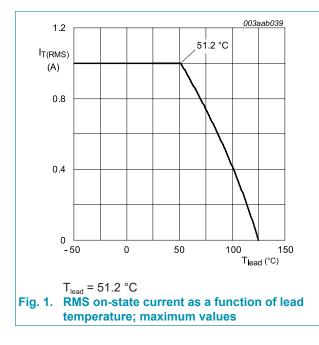
Table 4. Marking codes						
Type number	Marking codes					
BT131-600D	131-6D					

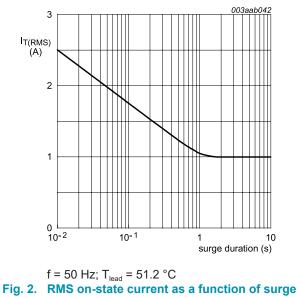
# 8. Limiting values

### Table 5. Limiting values

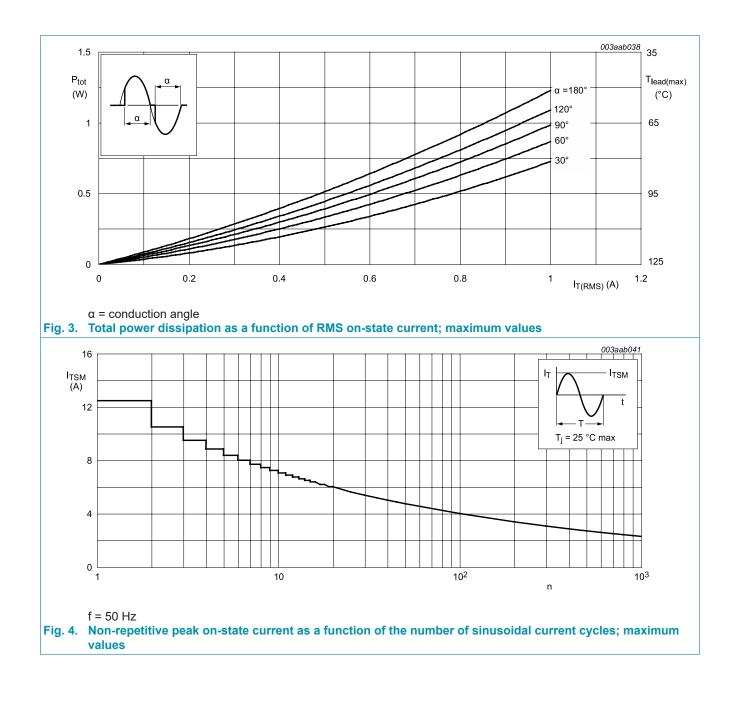
In accordance with the Absolute Maximum Rating System (IEC 60134).

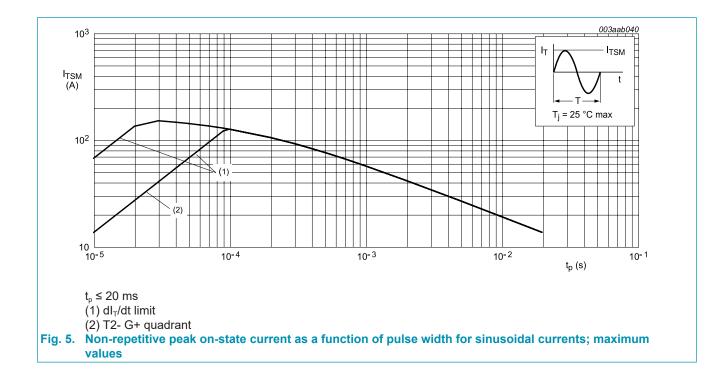
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	600	V
I <sub>T(RMS)</sub>	RMS on-state currentfull sine wave; $T_{lead} \le 51 \degree C$ ; Fig 1; Fig 2;Fig 3		-	1	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 20 ms; Fig 4; Fig 5	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	13.7	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>P</sub> = 10 ms; SIN	-	0.78	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state	I <sub>G</sub> = 10 mA	-	50	A/µs
	current	I <sub>G</sub> = 10 mA	-	50	A/µs
		I <sub>G</sub> = 14 mA	-	10	A/µs
		I <sub>G</sub> = 10 mA	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	2	Α
$P_{GM}$	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C





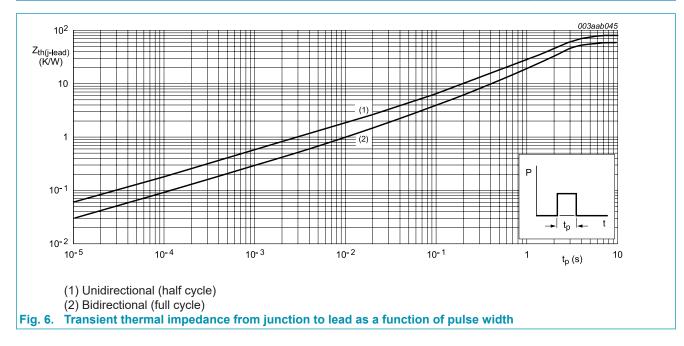
duration; maximum values





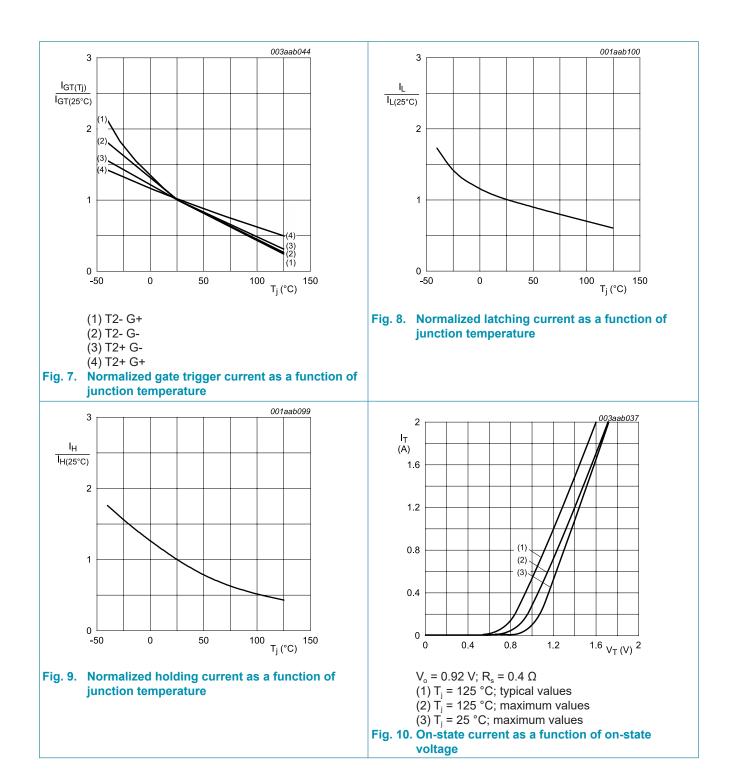
# 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance	full cycle; <u>Fig 6</u>	-	-	60	K/W
	from junction to lead	half cycle; <u>Fig 6</u>	-	-	80	K/W
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



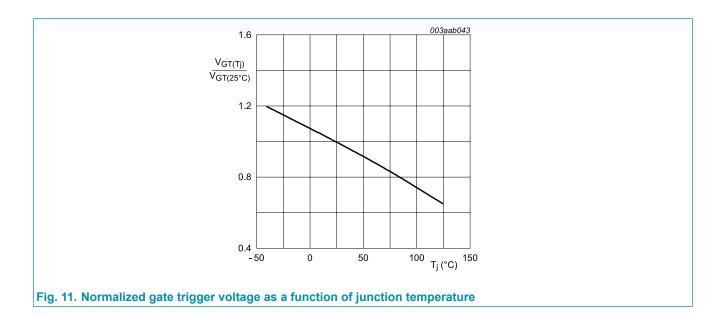
## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics	1				
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	-	5	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	5	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; Fig. 7	-	-	7	mA
IL	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$	-	-	10	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; Fig. 8	-	-	20	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G+};$ T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	10	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	1.3	10	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.4 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V <sub>GT</sub>	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C	0.2	0.3	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	· · · · ·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage		20	-	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage $V_D = 400 V; T_j = 125 °C; dI_{com}/dt = 0.5 A$ ms; $I_T = 1 A;$ gate open circuit		3	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 1.5 A; $V_D$ = 600 V; $I_G$ = 0.1 A; $dI_G/dt$ = 5 A/µs	-	2	-	μs

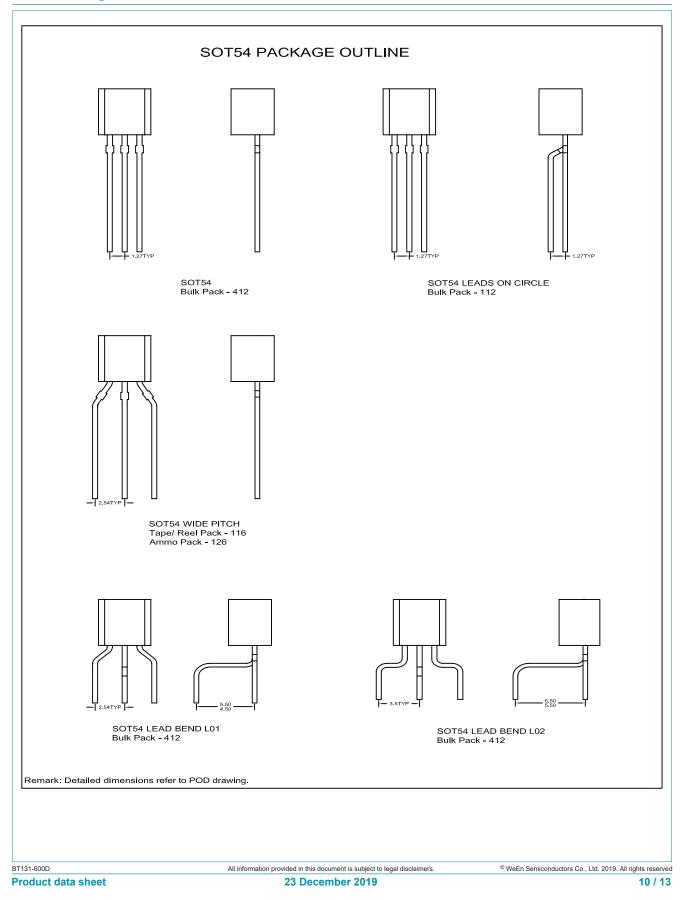


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# 11. Package outline



# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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